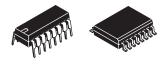
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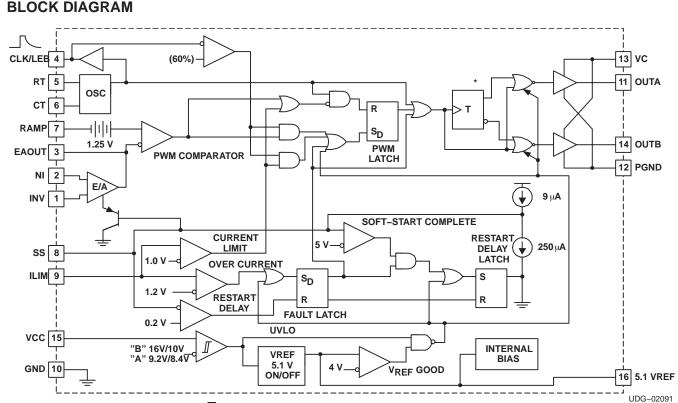
HIGH-SPEED PWM CONTROLLER

FEATURES

- Improved Versions of the UC3823/UC3825 PWMs
- Compatible with Voltage-Mode or Current-Mode Control Methods
- Practical Operation at Switching Frequencies to 1 MHz
- 50-ns Propagation Delay to Output
- High-Current Dual Totem Pole Outputs (2-A Peak)
- Trimmed Oscillator Discharge Current
- Low 100-μA Startup Current
- Pulse-by-Pulse Current Limiting Comparator
- Latched Overcurrent Comparator With Full Cycle Restart

DESCRIPTION

The UC3823A and UC3823B and the UC3825A and UC3825B family of PWM controllers are improved versions of the standard UC3823 and UC3825 family. Performance enhancements have been made to several of the circuit blocks. Error amplifier gain bandwidth product is 12 MHz, while input offset voltage is 2 mV. Current limit threshold is assured to a tolerance of 5%. Oscillator discharge current is specified at 10 mA for accurate dead time control. Frequency accuracy is improved to 6%. Startup supply current, typically 100 μ A, is ideal for off-line applications. The output drivers are redesigned to actively sink current during UVLO at no expense to the startup current specification. In addition each output is capable of 2-A peak currents during transitions.



* On the UC1823A version, toggles Q and \overline{Q} are always low.

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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

DESCRIPTION (CONTINUED)

Functional improvements have also been implemented in this family. The UC3825 shutdown comparator is now a high-speed overcurrent comparator with a threshold of 1.2 V. The overcurrent comparator sets a latch that ensures full discharge of the soft-start capacitor before allowing a restart. While the fault latch is set, the outputs are in the low state. In the event of continuous faults, the soft-start capacitor is fully charged before discharge to insure that the fault frequency does not exceed the designed soft start period. The UC3825 CLOCK pin has become CLK/LEB. This pin combines the functions of clock output and leading edge blanking adjustment and has been buffered for easier interfacing.

The UC3825A and UC3825B have dual alternating outputs and the same pin configuration of the UC3825. The UC3823A and UC3823B outputs operate in phase with duty cycles from zero to less than 100%. The pin configuration of the UC3823A and UC3823B is the same as the UC3823 except pin 11 is now an output pin instead of the reference pin to the current limit comparator. "A" version parts have UVLO thresholds identical to the original UC3823 and UC3825. The "B" versions have UVLO thresholds of 16 V and 10 V, intended for ease of use in off-line applications.

Consult the application note, *The UC3823A,B and UC3825A,B Enhanced Generation of PWM Controllers*, (SLUA125) for detailed technical and applications information.

ORDERING INFORMATION

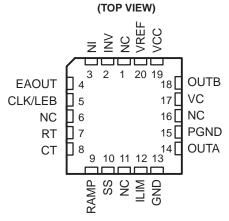
		UVLO						
Τ _Α	MAXIMUM		9.2 V / 8.4 V					
	DUTY CYCLE	SOIC-16 ⁽¹⁾ (DW)	PDIP-16 (N)	PLCC-20 ⁽¹⁾ (Q)	SOIC-16 (DW)	PDIP-16 (N)	PLCC-20 ⁽¹⁾ (Q)	
–40°C to 85°C	< 100%	UC2823ADW	UC2823AN	UC2823AQ	UC2823BDW	UC2823BN	-	
-40°C 10 85°C	< 50%	UC2825ADW	UC2825AN	UC2825AQ	UC2825BDW	UC2825BN	-	
000 10 7000	< 100%	UC3823ADW	UC3823AN	UC3823AQ	UC3823BDW	UC3823BN	-	
-0°C to 70°C	< 50%	UC3825ADW	UC3825AN	UC3825AQ	UC3825BDW	UC3825BN	UC3825BQ	

(1) The DW and Q packages are also available taped and reeled. Add TR suffix to the device type (i.e., UC2823ADWR). To order quantities of 1000 devices per reel for the Q package and 2000 devices per reel for the DW package.

		UV	LO				
Т	MAXIMUM	9.2 V / 8.4 V					
TA	DUTY CYCLE	CDIP-16	LCCC-20				
		(J)	(L)				
-55°C to 125°C	< 100%	UC1823AJ, UC1823AJ883B, UC1823AJQMLV	UC1823AL, UC1823AL883B				
-55 C 10 125 C	< 50%	UC1825AJ, UC1825AJ883B, UC1825AJQMLV	UC1825AL, UC1825AL883B, UC1825ALQMLV				

PIN ASSIGNMENTS

DW. J. OR N PACKAGES (TOP VIEW) INV **1** VREF 16 ΝΓ 2 15 l vcc EAOUT I 3 14 OUTB CLK/LEB 13 VC 4 RT 5 12 7 pgnd CT 6 11 OUTA RAMP 10 GND 7 SS 8 9] ILIM



Q OR L PACKAGES

NC = no connection



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TERMINAL FUNCTIONS

-	TERMINAL	MINAL							
NAME	N	0.	I/O	DESCRIPTION					
NAME	J or DW	Q or L							
CLK/LEB	4	5	0	Output of the internal oscillator					
СТ	6	8	I	Timing capacitor connection pin for oscillator frequency programming. The timing capacitor should be connected to the device ground using minimal trace length.					
EAOUT	3	4	0	Output of the error amplifier for compensation					
GND	10	13	_	Analog ground return pin					
ILIM	9	12	I	Input to the current limit comparator					
INV	1	2	I	Inverting input to the error amplifier					
NI	2	3	I	Non-inverting input to the error amplifier					
OUTA	11	14	0	High current totem pole output A of the on-chip drive stage.					
OUTB	14	18	0	High current totem pole output B of the on-chip drive stage.					
PGND	12	15	-	Ground return pin for the output driver stage					
RAMP	7	9	I	Non-inverting input to the PWM comparator with 1.25-V internal input offset. In voltage mode operation, this serves as the input voltage feed-forward function by using the CT ramp. In peak current mode operation, this serves as the slope compensation input.					
RT	5	7	I	Timing resistor connection pin for oscillator frequency programming					
SS	8	10	I	Soft-start input pin which also doubles as the maximum duty cycle clamp.					
VC	13	17	-	Power supply pin for the output stage. This pin should be bypassed with a 0.1 - μ F monolithic ceramic low ESL capacitor with minimal trace lengths.					
VCC	15	19	_	Power supply pin for the device. This pin should be bypassed with a 0.1 - μ F monolithic ceramic low ESL capacitor with minimal trace lengths					
VREF	16	20	0	5.1-V reference. For stability, the reference should be bypassed with a 0.1- μ F monolithic ceramic low ESL capacitor and minimal trace length to the ground plane.					

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range unless otherwise noted $^{(1)}$

			UNIT
VIN	Supply voltage,	VC, VCC	22 V
lo	Source or sink current, DC	OUTA, OUTB	0.5 A
IO	Source or sink current, pulse (0.5 µs)	OUTA, OUTB	2.2 A
		INV, NI, RAMP	–0.3 V to 7 V
	Analog inputs	ILIM, SS	–0.3 V to 6 V
	Power ground	PGND	±0.2 V
ICLK	Clock output current	CLK/LEB	–5 mA
IO(EA)	Error amplifier output current	EAOUT	5 mA
ISS	Soft-start sink current	SS	20 mA
losc	Oscillator charging current	RT	–5 mA
Тј	Operating virtual junction temperature ra	ange	–55°C to 150°C
T _{stg}	Storage temperature		-65°C to 150°C
	Lead temperature 1,6 mm (1/16 inch) fr	om case for 10 seconds	-55C°C to 150°C
^t STG	Storage temperature		–65°C to 150°C
	Lead temperature 1,6 mm (1/16 inch) fr	300°C	

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



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ELECTRICAL CHARACTERISTICS

 $T_A = -55^{\circ}C$ to 125°C for the UC1823A/UC1825A, $T_A = -40^{\circ}C$ to 85°C for the UC2823x/UC2825x, $T_A = 0^{\circ}C$ to 70°C for the UC3823x/UC3825x, $R_T = 3.65 \text{ k}\Omega$, $C_T = 1 \text{ nF}$, $V_{CC} = 12 \text{ V}$, $T_A = T_J$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
REFERE	ENCE, V _{REF}					
VO	Ouput voltage range	$T_J = 25^{\circ}C$, $I_O = 1 \text{ mA}$	5.05	5.1	5.15	V
	Line regulation	$12 \text{ V} \leq \text{ VCC } \leq 20 \text{ V}$		2	15	
	Load regulation	$1 \text{ mA} \le I_O \le 10 \text{ mA}$		5	20	mv
	Total output variation	Line, load, temperature	5.03		5.17	V
	Temperature stability ⁽¹⁾	$T_{(min)} < T_A < T_{(max)}$		0.2	0.4	mV/°C
	Output noise voltage(1)	10 Hz < f < 10 kHz		50		μVRMS
	Long term stability ⁽¹⁾	T _J = 125°C, 1000 hours		5	25	mV
	Short circuit current	VREF = 0 V	30	60	90	mA
OSCILL	ATOR		•			•
		TJ = 25°C	375	400	425	kHz
fosc	Initial accuracy ⁽¹⁾	$R_T = 6.6 \text{ k}\Omega, C_T = 220 \text{ pF}, T_A = 25^{\circ}C$	0.9	1	1.1	15 V 15 mV 20 mV 17 V 17 V 14 mV/°C µVRMS 25 mV 90 mA 25 kHz 1 MHz 50 kHz 15 MHz 90 v 23 V 25 V 21 mA 0 mV 3 µA 1 mA 3 µA 1 mA 3 µA 1 mA 3 µA 1 mA 5 V 1 Mhz
	T (1)	Line, temperature	350		450	kHz
	Total variation ⁽¹⁾	$R_T = 6.6 \text{ k}\Omega, C_T = 220 \text{ pF},$	0.85		1.15	MHz
	Voltage stability	12 V < VCC < 20 V			1%	
	Temperature stability ⁽¹⁾	$T_{(min)} < T_A < T_{(max)}$	+/-	5%		
	High-level output voltage, clock		3.7	4		
	Low-level output voltage, clock			0	0.2	
	Ramp peak		2.6	2.8	3	V
	Ramp valley		0.7	1	1.25	
	Ramp valley-to-peak		1.6	1.8	2	
losc	Oscillator discharge current	$R_T = OPEN, V_{CT} = 2 V$	9	10	11	mA
ERROR	AMPLIFIER		·			
	Input offset voltage			2	10	mV
	Input bias current			0.6	3	
	Input offset current			0.1	1	μA
	Open loop gain	1 V < V _O < 4 V	60	95		
CMRR	Common mode rejection ratio	1.5 V < V _{CM} < 5.5 V	75	95		dB
PSRR	Power supply rejection ratio	12 V < V _{CC} < 20 V	85	110		
lO(sink)	Output sink current	VEAOUT = 1 V	1	2.5		
IO(src)	Output source current	VEAOUT = 4 V	-0.5	-1.3		mA
. /	High-level output voltage	IEAOUT = -0.5 mA	4.5	4.7	5	
	Low-level output voltage	IEAOUT = -1 mA	0	0.5	1	V
	Gain bandwidth product	f = 200 kHz	6	12		Mhz
	Slew rate(1)		6	9		V/µs

(1) Ensured by design. Not production tested.

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ELECTRICAL CHARACTERISTICS

 $T_{A} = -55^{\circ}C \text{ to } 125^{\circ}C \text{ for the UC1823A/UC1825A}, T_{A} = -40^{\circ}C \text{ to } 85^{\circ}C \text{ for the UC2823x/UC2825x}, T_{A} = 0^{\circ}C \text{ to } 70^{\circ}C \text{ for the UC3823x/UC3825x}, R_{T} = 3.65 \text{ k}\Omega, C_{T} = 1 \text{ nF}, V_{CC} = 12 \text{ V}, T_{A} = T_{J} \text{ (unless otherwise noted)}$

PWM C	OMPARATOR					
IBIAS	Bias current, RAMP	V _{RAMP} = 0 V		-1	-8	μΑ
	Minimum duty cycle				0%	
	Maximum duty cycle		85%			
^t LEB	Leading edge blanking time	$R_{LEB} = 2 k\Omega$, $C_{LEB} = 470 pF$	300	375	450	ns
R _{LEB}	Leading edge blanking resistance	V _{CLK/LEB} = 3 V	8.5	10.0	11.5	kΩ
VZDC	Zero dc threshold voltage, EAOUT	$V_{RAMP} = 0 V$	1.10	1.25	1.4	V
^t DELAY	Delay-to-output time	VEAOUT = 2.1 V, VILIM = 0 V to 2 V step		50	80	ns
CURRE	NT LIMIT / START SEQUENCE / FAULT					
ISS	Soft-start charge current	V _{SS} = 2.5 V	8	14	20	μΑ
VSS	Full soft-start threshold voltage		4.3	5		V
IDSCH	Restart discharge current	V _{SS} = 2.5 V	100	250	350	μA
Iss	Restart threshold voltage			0.3	0.5	V
IBIAS	ILIM bias current	V _{ILIM} = 0 V to 2 V step			15	μA
ICL	Current limit threshold voltage		0.95	1	1.05	.,
	Overcurrent threshold voltage		1.14	1.2	1.26	V
td	Delay-to-output time, ILIM ⁽¹⁾	V _{ILIM} = 0 V to 2 V step		50	80	ns
OUTPU	т					
		I _{OUT} = 20 mA		0.25	0.4	
	Low-level output saturation voltage	I _{OUT} = 200 mA		1.2	2.2	.,
		I _{OUT} = 20 mA		1.9	2.9	V
	High-level output saturation voltage	I _{OUT} = 200 mA		2	3	
t _{r,} tf	Rise/fall time(1)	C _L = 1 nF		20	45	ns
UNDER	VOLTAGE LOCKOUT (UVLO)	·	•			
		UC2823B, UC2825B, UC3825B, UC3825B		16	17	
	Start threshold voltage	UC1823A, UC1825A, UC2823A, UC2825A UC3825A, UC3825A	8.4	9.2	9.6	
	Stop threshold voltage	UC2823B, UC2825B, UC3825B, UC3825B	9	10		V
	OVLO hysteresis	UC1823A, UC1825A, UC2823A, UC2825A UC3825A, UC3825A	0.4	0.8	1.2	
	-	UC2823B, UC2825B, UC3825B, UC3825B	5	6	7	
SUPPLY	CURRENT					
I _{su}	Startup current	$VC = VCC = V_{TH} = -0.5 V$		100	300	μΑ
ICC	Input current			28	36	mA

(1) Ensured by design. Not production tested.



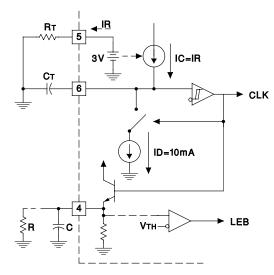
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APPLICATION INFORMATION

The oscillator of the UC3823A, UC3823B, UC3825A, and UC3825B is a saw tooth. The rising edge is governed by a current controlled by the RT pin and value of capacitance at the CT pin (C_{CT}). The falling edge of the sawtooth sets dead time for the outputs. Selection of RT should be done first, based on desired maximum duty cycle. CT can then be chosen based on the desired frequency (RT) and D_{MAX} . The design equations are:

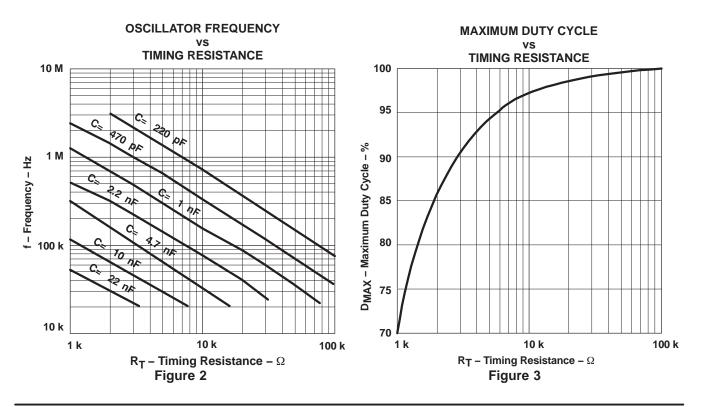
$$R_{T} = \frac{3 V}{(10 \text{ mA}) \times (1 - D_{MAX})} \qquad C_{T} = \frac{(1.6 \times D_{MAX})}{(R_{T} \times f)}$$
(1)

Recommended values for R_T range from 1 k Ω to 100 k Ω . Control of D_{MAX} less than 70% is not recommended.



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Figure 1. Oscillator





LEADING EDGE BLANKING

The UC3823A, UC2823B, UC3825A, and UC3825B perform fixed frequency pulse width modulation control. The UC3823A, and UC3823B outputs operate together at the switching frequency and can vary from zero to some value less than 100%. The UC3825A and UC3825B outputs are alternately controlled. During every other cycle, one output is off. Each output then switches at one-half the oscillator frequency, varying in duty cycle from 0 to less than 50%.

To limit maximum duty cycle, the internal clock pulse blanks both outputs low during the discharge time of the oscillator. On the falling edge of the clock, the appropriate output(s) is driven high. The end of the pulse is controlled by the PWM comparator, current limit comparator, or the overcurrent comparator.

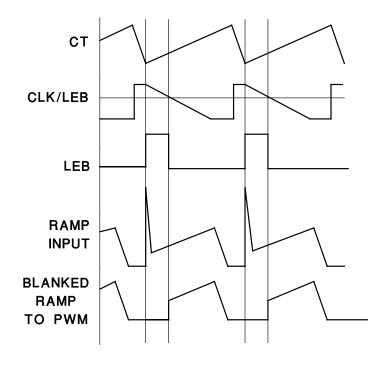
Normally the PWM comparator senses a ramp crossing a control voltage (error amplifier output) and terminates the pulse. Leading edge blanking (LEB) causes the PWM comparator to be ignored for a fixed amount of time after the start of the pulse. This allows noise inherent with switched mode power conversion to be rejected. The PWM ramp input may not require any filtering as result of leading edge blanking.

To program a leading edge blanking (LEB) period, connect a capacitor, C, to CLK/LEB. The discharge time set by C and the internal $10-k\Omega$ resistor determines the blanked interval. The $10-k\Omega$ resistor has a 10% tolerance. For more accuracy, an external $2-k\Omega$ 1% resistor (R) can be added, resulting in an equivalent resistance of $1.66 k\Omega$ with a tolerance of 2.4%. The design equation is:

 $t_{I FB} = 0.5 \times (R \parallel 10 \text{ k}\Omega) \times C$

Values of R less than 2 k Ω should not be used.

Leading edge blanking is also applied to the current limit comparator. After LEB, if the ILIM pin exceeds the 1-V threshold, the pulse is terminated. The overcurrent comparator, however, is not blanked. It catches catastrophic overcurrent faults without a blanking delay. Any time the ILIM pin exceeds 1.2 V, the fault latch is set and the outputs driven low. For this reason, some noise filtering may be required on the ILIM pin.



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(2)

Figure 4. Leading Edge Blanking Operational Waveforms



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UVLO, SOFT-START AND FAULT MANAGEMENT

Soft-start is programmed by a capacitor on the SS pin. At power up, SS is discharged. When SS is low, the error amplifier output is also forced low. While the internal 9-µA source charges the SS pin, the error amplifier output follows until closed loop regulation takes over.

Anytime ILIM exceeds 1.2 V, the fault latch is set and the output pins are driven low. The soft-start cap is then discharged by a 250-µA current sink. No more output pulses are allowed until soft-start is fully discharged and ILIM is below 1.2 V. At this point the fault latch resets and the chip executes a soft-start.

Should the fault latch get set during soft-start, the outputs are immediately terminated, but the soft-start capacitor does not discharge until it has been fully charged first. This results in a controlled hiccup interval for continuous fault conditions.

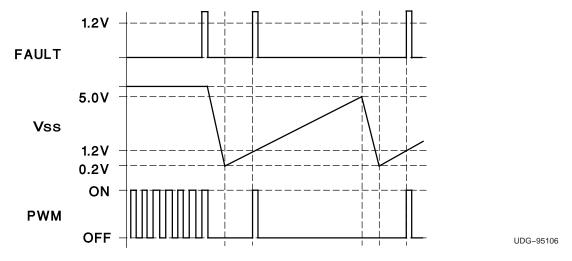


Figure 5. Soft-Start and Fault Waveforms

ACTIVE LOW OUTPUTS DURING UVLO

The UVLO function forces the outputs to be low and considers both VCC and VREF before allowing the chip to operate.

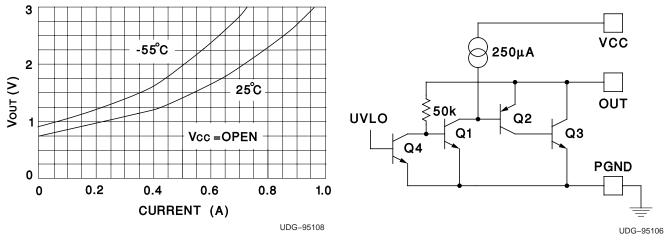


Figure 6. Output Voltage vs Output Current

Figure 7. Output V and I During UVLO



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CONTROL METHODS

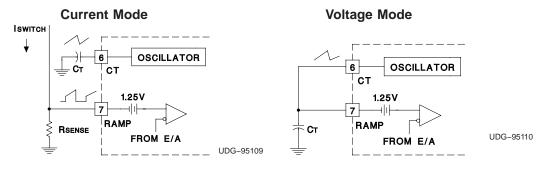


Figure 8. Control Methods

SYNCHRONIZATION

The oscillator can be synchronized by an external pulse inserted in series with the timing capacitor. Program the free running frequency of the oscillator to be 10% to 15% slower than the desired synchronous frequency. The pulse width should be greater than 10 ns and less than half the discharge time of the oscillator. The rising edge of the CLK/LEB pin can be used to generate a synchronizing pulse for other chips. Note that the CLK/LEB pin no longer accepts an incoming synchronizing signal.

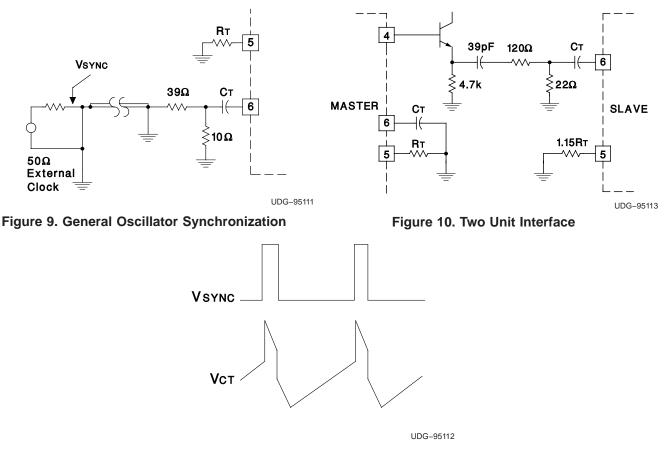


Figure 11. Operational Waveforms



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HIGH CURRENT OUTPUTS

Each totem pole output of the UC3823A and UC3823AB, UC3825A, and UC3825B can deliver a 2-A peak current into a capacitive load. The output can slew a 1000-pF capacitor by 15 V in approximately 20 ns. Separate collector supply (VC) and power ground (PGND) pins help decouple the device's analog circuitry from the high-power gate drive noise. The use of 3-A Schottky diodes (1N5120, USD245, or equivalent) as shown in the Figure 13 from each output to both VC and PGND are recommended. The diodes clamp the output swing to the supply rails, necessary with any type of inductive/capacitive load, typical of a MOSFET gate. Schottky diodes must be used because a low forward voltage drop is required. DO NOT USE standard silicon diodes.

Although they are *single-ended* devices, two output drivers are available on the UC3823A and UC3823B devices. These can be *paralleled* by the use of a 0.5 Ω (noninductive) resistor connected in series with each output for a combined peak current of 4 A.

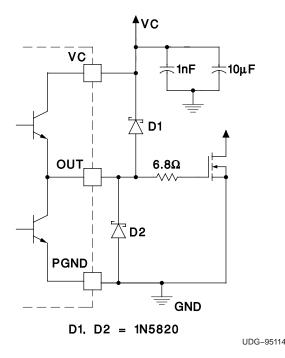


Figure 12. Power MOSFET Drive Circuit

GROUND PLANES

Each output driver of these devices is capable of 2-A peak currents. Careful layout is essential for correct operation of the chip. A ground plane must be employed. A unique section of the ground plane must be designated for high di/dt currents associated with the output stages. This point is the power ground to which the PGND pin is connected. Power ground can be separated from the rest of the ground plane and connected at a single point, although this is not necessary if the high di/dt paths are well understood and accounted for. VCC should be bypassed directly to power ground with a good high frequency capacitor. The sources of the power MOSFET should connect to power ground as should the return connection for input power to the system and the bulk input capacitor. The output should be clamped with a high current Schottky diode to both VCC and PGND. Nothing else should be connected to power ground.

VREF should be bypassed directly to the signal portion of the ground plane with a good high frequency capacitor. Low ESR/ESL ceramic 1-mF capacitors are recommended for both VCC and VREF. All analog circuitry should likewise be bypassed to the signal ground plane.



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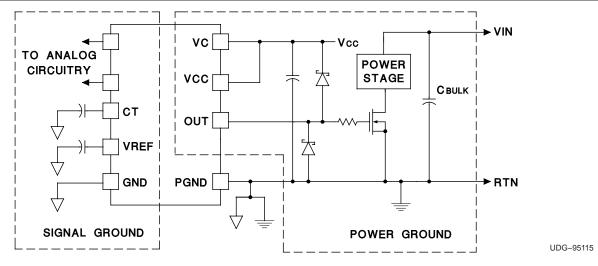


Figure 13. Ground Planes Diagram

OPEN LOOP TEST CIRCUIT

This test fixture is useful for exercising many functions of this device family and measuring their specifications. As with any wideband circuit, careful grounding and bypass procedures should be followed. The use of a ground plane is highly recommended.

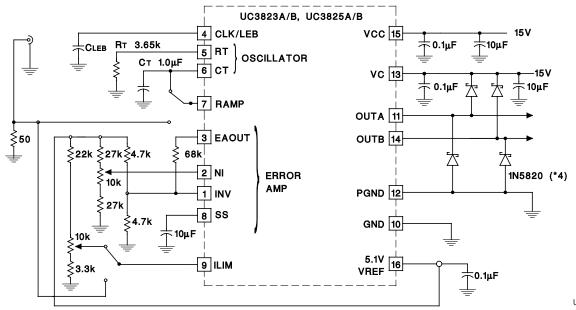


Figure 14. Open Loop Test Circuit Schematic

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PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	n MSL Peak Temp ⁽³⁾
5962-87681022A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
5962-8768102EA	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
5962-8768102V2A	ACTIVE	LCCC	FK	20	1	TBD	Call TI	N / A for Pkg Type
5962-8768102VEA	ACTIVE	CDIP	J	16	1	TBD	Call TI	N / A for Pkg Type
5962-8768102XA	OBSOLETE	TO-92	LP	28		TBD	Call TI	N / A for Pkg Type
5962-8768103XA	OBSOLETE	TO-92	LP	28		TBD	Call TI	N / A for Pkg Type
5962-89905022A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
5962-8990502EA	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
5962-8990502VEA	ACTIVE	CDIP	J	16	1	TBD	Call TI	N / A for Pkg Type
UC1823AJ	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
UC1823AJ883B	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
UC1823AJQMLV	ACTIVE	CDIP	J	16		TBD	Call TI	Call TI
UC1823AL	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
UC1823AL883B	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
UC1823BJ	OBSOLETE	CDIP	J	16		TBD	Call TI	Call TI
UC1823BJ883B	OBSOLETE	CDIP	J	16		TBD	Call TI	Call TI
UC1823BL	OBSOLETE	LCCC	FK	20		TBD	Call TI	Call TI
UC1823BL883B	OBSOLETE	LCCC	FK	20		TBD	Call TI	Call TI
UC1825AJ	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
UC1825AJ883B	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
UC1825AJQMLV	ACTIVE	CDIP	J	16		TBD	Call TI	Call TI
UC1825AL	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
UC1825AL883B	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
UC1825ALP883B	OBSOLETE	TO-92	LP	28		TBD	Call TI	N / A for Pkg Type
UC1825ALQMLV	ACTIVE	LCCC	FK	20		TBD	Call TI	Call TI
UC1825BJ	OBSOLETE	CDIP	J	16		TBD	Call TI	Call TI
UC1825BJ883B	OBSOLETE	CDIP	J	16		TBD	Call TI	Call TI
UC1825BL/81047	OBSOLETE	TO/SOT	L	20		TBD	Call TI	Call TI
UC1825BL883B	OBSOLETE	LCCC	FK	20		TBD	Call TI	Call TI
UC1825BLP883B	OBSOLETE	TO-92	LP	28		TBD	Call TI	N / A for Pkg Type
UC2823ADW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
UC2823ADWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
UC2823ADWTR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
UC2823ADWTRG4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
UC2823AN	ACTIVE	PDIP	Ν	16	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type
UC2823ANG4	ACTIVE	PDIP	Ν	16	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type
UC2823AQ	ACTIVE	PLCC	FN	20	46	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR

PACKAGE OPTION ADDENDUM

19-Jun-2007

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Packag Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³
UC2823BDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAI
UC2823BDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
UC2823BJ	OBSOLETE	CDIP	J	16		TBD	Call TI	Call TI
UC2823BN	ACTIVE	PDIP	Ν	16	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type
UC2823BNG4	ACTIVE	PDIP	Ν	16	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type
UC2825ADW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
UC2825ADWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
UC2825ADWTR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
UC2825ADWTRG4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
UC2825AN	ACTIVE	PDIP	N	16	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type
UC2825ANG4	ACTIVE	PDIP	N	16	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type
UC2825AQ	ACTIVE	PLCC	FN	20	46	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEA
UC2825AQG3	ACTIVE	PLCC	FN	20	46	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEA
UC2825BDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
UC2825BDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
UC2825BDWTRG4	ACTIVE	SOIC	DW	16		TBD	Call TI	Call TI
UC2825BJ	OBSOLETE	CDIP	J	16		TBD	Call TI	Call TI
UC2825BN	ACTIVE	PDIP	N	16	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type
UC2825BNG4	ACTIVE	PDIP	Ν	16	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type
UC3823ADW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
UC3823ADWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
UC3823ADWTR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
UC3823ADWTRG4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
UC3823AN	ACTIVE	PDIP	Ν	16	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type
UC3823ANG4	ACTIVE	PDIP	Ν	16	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type
UC3823BDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA
UC3823BDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEA

TEXAS INSTRUMENTS www.ti.com

PACKAGE OPTION ADDENDUM

19-Jun-2007

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Packag Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
UC3823BDWTR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
UC3823BDWTRG4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
UC3823BN	ACTIVE	PDIP	Ν	16	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type
UC3823BNG4	ACTIVE	PDIP	Ν	16	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type
UC3825ADW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
UC3825ADWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
UC3825ADWTR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
UC3825ADWTRG4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
UC3825AN	ACTIVE	PDIP	Ν	16	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type
UC3825ANG4	ACTIVE	PDIP	Ν	16	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type
UC3825AQ	ACTIVE	PLCC	FN	20	46	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR
UC3825AQG3	ACTIVE	PLCC	FN	20	46	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR
UC3825AQTRG3	ACTIVE	PLCC	FN	20		TBD	Call TI	Call TI
UC3825BDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
UC3825BDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
UC3825BDWTR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
UC3825BDWTRG4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
UC3825BN	ACTIVE	PDIP	N	16	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type
UC3825BNG4	ACTIVE	PDIP	Ν	16	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS



compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

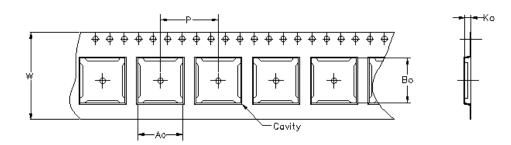
⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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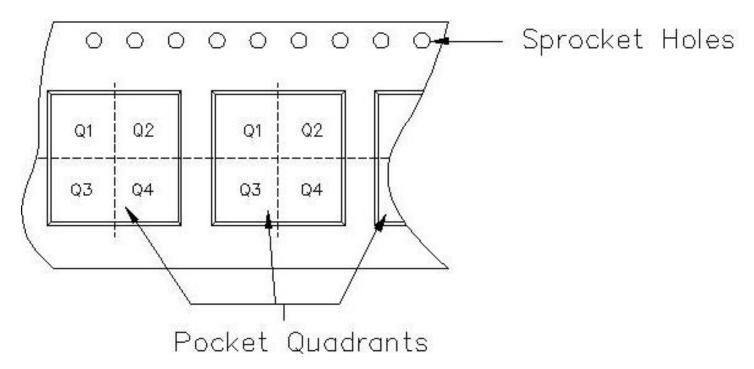


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Carrier tape design is defined largely by the component lentgh, width, and thickness.

Ao = Dimension designed to accommodate the component width.								
Bo = Dimension designed to accommodate the component length.								
Ko = Dimension designed to accommodate the component thickness.								
W = Overall width of the carrier tape.								
P = Pitch between successive cavity centers.								



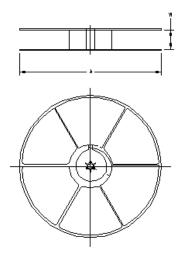
TAPE AND REEL INFORMATION

PACKAGE MATERIALS INFORMATION



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Device	Package	Pins	Site	Reel Diameter (mm)	Reel Width (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
UC2823ADWTR	DW	16	MLA	330	16	10.85	10.8	2.7	12	16	Q1
UC2825ADWTR	DW	16	MLA	330	16	10.85	10.8	2.7	12	16	Q1
UC3823ADWTR	DW	16	MLA	330	16	10.85	10.8	2.7	12	16	Q1
UC3823BDWTR	DW	16	MLA	330	16	10.85	10.8	2.7	12	16	Q1
UC3825ADWTR	DW	16	MLA	330	16	10.85	10.8	2.7	12	16	Q1
UC3825BDWTR	DW	16	MLA	330	16	10.85	10.8	2.7	12	16	Q1



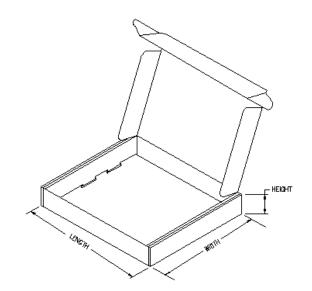
TAPE AND REEL BOX INFORMATION

Device	Package	Pins	Site	Length (mm)	Width (mm)	Height (mm)
UC2823ADWTR	DW	16	MLA	0.0	0.0	0.0
UC2825ADWTR	DW	16	MLA	0.0	0.0	0.0
UC3823ADWTR	DW	16	MLA	0.0	0.0	0.0
UC3823BDWTR	DW	16	MLA	0.0	0.0	0.0
UC3825ADWTR	DW	16	MLA	0.0	0.0	0.0
UC3825BDWTR	DW	16	MLA	0.0	0.0	0.0



PACKAGE MATERIALS INFORMATION

15-Jun-2007



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